

In Class Quiz 1: Submit via Canvas

- Subtract 8 from 9 in 2's complement negation method (without doing subtraction)
- Assume we have 8-bit digits (not 32 bits), ignore carry beyond 8 bits
- 9 in binary: 0000_1001
- 8 in binary: 0000_1000
- Step 1: -8 in binary: ?
- Step 2: 9+(-8) in binary:?

30

1

0.5 / 0.5 points

Show the correct work to subtract 8 from 9 in 2's complement negation method (without doing subtraction) Assume we have 8-bit digits (not 32 bits), ignore carry beyond 8 bits.

☐ Step1: -8 in binary: 1111_0111

Step2: 9+(-8) in binary: 0000_1001+1111_0111



☒ Step1: -8 in binary: 1111_0111+1= 1111_1000

Step2: 9+(-8) in binary: 0000_1001+1111_1000

☐ Step1: -8 in binary: 0000_1000+1= 0000_1001

Step2: 9+(-8) in binary: 0000_1001+0000_1001

☐ Step1: -8 in binary: 0111_0111+1= 0111_1000

Step2: 9+(-8) in binary: 0000_1001+0111_1000

Quiz 2:

- Assume reg t1, t2 contains decimal 4 and 1000 respectively. Reg \$zero contains 0.
- All numbers in decimal. **Submit via Canvas**
- **Question 1: How many times the instruction “add t2, t2, t1” will execute?**
- **Question 2: To which memory address content of \$t2 is stored?**

```
loop: add $t2, $t2, $t1  
addi $t1, $t1, -1  
bne $t1, $zero loop  
sw $t2, 104($t1)
```

26

1

0.25 / 0.25 points

How many times the instruction “add t2, t2, t1” will execute?

☐ 0

☒ 4

☐ 2

☐ 3

2

0.25 / 0.25 points

To which memory address content of \$t2 is stored?

☐ 4

☐ 0

☒ 104

☐ 108

THIS IS QUIZ 3

1

0.25 / 0.25 points

Which features of NAND flash makes it less attractive technology (compared to NOR flash) for storing program's binary on an embedded platform?

- ☐ Read granularity of 1 byte
- ☐ Higher density (storage capacity per area)



☒ Read granularity of 1 page (e.g, 512 Byte)



☒ Slow random reads

2

0.25 / 0.25 points

Which of the following memory technologies are non-volatile?

- ☐ SRAM



☒ EEPROM

- ☐ Register



☒ Solid state drive

- ☐ DRAM